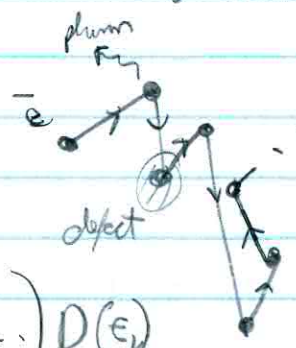


The drift-diffusion eqn:

Lecture # 23 : Thermal conductivity and electrical conductivity

▶ The interaction of electrons with defects and phonons leads to a mean relaxation time τ for electrons $l = \bar{v} \tau$. How to relate electrical conductivity to τ ?

↑ mean free path
↑ mean time between collisions "relaxation time"



$$\frac{1}{\tau_k} = \frac{2\pi}{\hbar} (|V_{e-phon}|^2 + |V_{e-defect}|^2 + \dots) D(\epsilon_k)$$

• Ballistic versus diffusive behavior.

▶ Same for phonons: But in insulators, phonons carry heat \Rightarrow Heat conductivity is determined by τ !

Diffusion eqn approach: Describe motion of particles at scales $x \gg l$.

Left \rightarrow right
 $N_{\text{particles}} = A \frac{\bar{v} t}{2} \rho \Rightarrow \frac{1}{A} \frac{dN_{\text{particles}}}{dt} = \underbrace{\rho}_{\text{flux or current density}} = \frac{1}{2} \bar{v} \rho x - dx$

(2)

Similarly, $G_x^- = \frac{1}{2} \bar{N}_x m_{x+dx}$

Total current:

$$G_x = G_x^+ - G_x^- = \bar{N}_x \left(\frac{m_{x-dx} - m_{x+dx}}{2dx} \right) dx$$

↓
Take smallest possible value of dx , $dx = l_x$ (mean free path)

$$\Rightarrow G_x = \underbrace{-\bar{N}_x}_{=\frac{\bar{N}}{\sqrt{3}}} \underbrace{(\bar{N}_x l_x)}_l \frac{\partial m}{\partial x} = \underbrace{-\left(\frac{1}{3} \bar{N}^2 \tau\right)}_D \frac{\partial m}{\partial x} = -D \frac{\partial m}{\partial x}$$

(Assumed $\bar{N}^2 = \bar{N}_x^2 + \bar{N}_y^2 + \bar{N}_z^2 = 3\bar{N}_x^2$)

Define Diffusion constant as

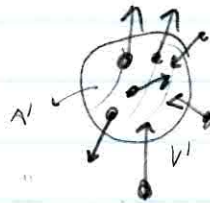
$$D = \frac{1}{3} \bar{N}^2 \tau = \frac{1}{3} \frac{l^2}{\tau}$$

$$\Rightarrow \boxed{\vec{G} = -D \vec{\nabla} m}$$

"Diffusion approximation": $m(\vec{r})$ changes slowly on the scale $\lambda \sim l$

Can also write $\vec{G} = m \vec{N} \Rightarrow \boxed{\vec{N} = -D \frac{\vec{\nabla} m}{m}}$
(where \vec{N} is a drift velocity).

Conservation law: # of particles is conserved



$$\frac{\partial}{\partial t} \left(\int_{V'} d^3n m(\vec{r}) \right) = \int_{A'} dA (\text{Flux in} - \text{Flux out}) = - \int_{A'} d\vec{A} \cdot \vec{G}$$

$$\int_{V'} d^3n \frac{\partial m(\vec{r})}{\partial t} = - \int_{V'} d^3n \nabla \cdot \vec{G} \Rightarrow \int_{V'} d^3n \left(\frac{\partial m}{\partial t} + \nabla \cdot \vec{G} \right) = 0 \quad \forall V'$$

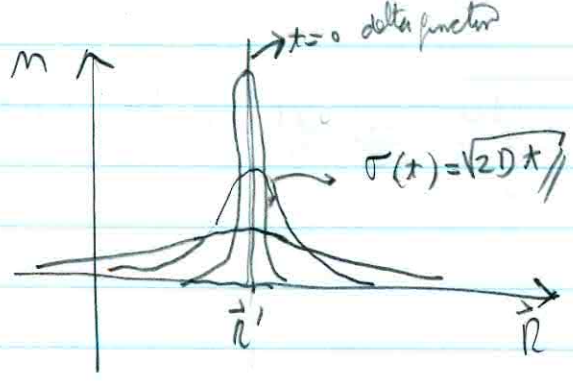
whenever V'

$$\Rightarrow \frac{\partial m}{\partial t} = -\vec{\nabla} \cdot \vec{G} = -\vec{\nabla} \cdot (-D \vec{\nabla} m) = D \nabla^2 m$$

$$\frac{\partial m}{\partial t} = D \nabla^2 m$$

Diffusion eqn.

if at $t=0$, $m(\vec{n}, t=0) = \delta(\vec{n}-\vec{n}')$ $\Rightarrow m(\vec{n}, t) = \frac{e^{-\frac{|\vec{n}-\vec{n}'|^2}{4Dt}}}{(4\pi Dt)^{3/2}}$



$$\langle x^2 \rangle = \sigma^2 = 2Dt$$

$\Rightarrow \sqrt{\langle x^2 \rangle} \propto \sqrt{t}$ "Brownian motion"
(Einstein's Ph.D. thesis)

For any ^{initial} condition $m(\vec{n}, t=0)$:

$$m(\vec{n}, t) = \int d^3 n' m(\vec{n}', t=0) \frac{e^{-\frac{|\vec{n}-\vec{n}'|^2}{4Dt}}}{(4\pi Dt)^{3/2}}$$

"Green's func"

↑
This is the general solution of the Diffusion eqn.

④

Thermal Conductivity (phonon current in insulators)

u = energy density

$$du = \bar{E} \, dn \quad \Rightarrow \quad \frac{\partial u}{\partial T} = D_u \nabla^2 u$$

\bar{E} \leftarrow avg energy of phonons
 dn \leftarrow avg # of phonons

$$\left(D_u = \frac{1}{3} \bar{v}^2 \tau \right)$$

From $C_v = \left(\frac{\partial U}{\partial T} \right)_V = V \left(\frac{\partial u}{\partial T} \right)_V \Rightarrow (dT) = \frac{V du}{C_v} \Rightarrow \frac{\partial T}{\partial x} = \frac{V}{C_v} \frac{\partial u}{\partial x} = \frac{V}{C_v} D_u \nabla^2 u$

$$\Rightarrow \boxed{\frac{\partial T}{\partial x} = D \nabla^2 T}$$

Energy flux or current: $\vec{Q} = u \vec{v} = -D_u \vec{\nabla} u = -K \vec{\nabla} T$

\downarrow
 "Thermal conductivity"

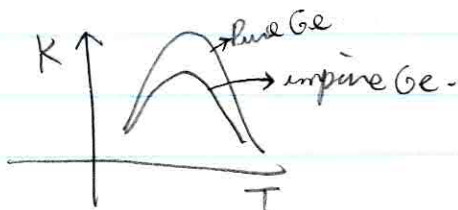
Use $dT = \frac{V}{C_v} du \Rightarrow -D_u \frac{C_v}{V} \vec{\nabla} T = -K \vec{\nabla} T$

$$\Rightarrow \boxed{K = \frac{D_u C_v}{V}}$$

At low T , expect $l \rightarrow \infty \rightarrow \underset{\substack{\uparrow \\ \text{size of sample}}}{L} \Rightarrow D = \frac{\bar{v} l}{3} \approx \frac{\bar{v} L}{3} = \text{const}$

Low $T \Rightarrow K \propto C_v \propto T^3$ increases with increasing T

High $T \Rightarrow \frac{1}{\tau} \propto \omega^5 \propto T^5 \Rightarrow D = \frac{\bar{v}^2}{3} \tau \propto T^{-5} \Rightarrow K \propto T^{-5} \Rightarrow$ decreases with increasing T .



Electrical conductivity

Electric field produces a drift: $\vec{a} = \frac{d\vec{v}}{dt} = \frac{\vec{F}}{m} = \frac{q}{m} \vec{E}$

↓
 \vec{F} is "drift force"

Assuming the electron propagates "ballistically" until it scatters:

$$\langle \vec{v} \rangle = \vec{a} \langle t \rangle = \vec{a} \tau = \frac{q}{m} \vec{E} \tau$$

Current density: $\vec{J} = q \vec{v} n = q \frac{q}{m} \vec{E} \tau n = \underbrace{q^2 \tau n}_\sigma \vec{E}$

Def. of electrical conductivity: $\vec{J} = \sigma \vec{E}$

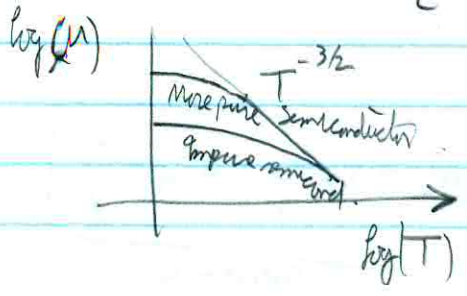
$$\sigma = \frac{q^2 \tau n}{m} = q \mu n \Rightarrow \boxed{\mu = \frac{q \tau}{m}}$$

where $\vec{v} = \mu \vec{E}$ is def. of mobility

D and μ are connected by τ : $D = \frac{1}{3} \langle v^2 \rangle \tau = \frac{1}{3} \cdot \frac{3}{2} k_B T \cdot \frac{m \mu}{q} = \frac{k_B T \mu}{q}$
 "Einstein's Relation!"

High T \Rightarrow e-ph scattering dominates $\frac{1}{\tau} \propto T^{3/2} \Rightarrow \mu \propto \tau \propto T^{-3/2}$

Low T \Rightarrow e-defect dominates $\frac{1}{\tau}$ independent of T
 (Because when $(ka) \ll 1$, e-defect is independent of k)



6

Drift + diffusion

Combine both effects:

$$\vec{N} = -D \frac{\vec{\nabla} m}{m} + \frac{\tau}{m} \vec{F}$$

$$m \vec{N} = -D \vec{\nabla} m + \frac{\tau}{m} m \vec{F} \Rightarrow \vec{\nabla} \cdot (m \vec{N}) = -D \nabla^2 m + \frac{\tau}{m} \vec{\nabla} \cdot (m \vec{F})$$

But from particle conservation, the left hand side equals to $-\frac{\partial m}{\partial t}$:

$$\frac{\partial m}{\partial t} = D \nabla^2 m - \frac{\tau}{m} \vec{\nabla} \cdot (m \vec{F})$$

Assume: $\begin{cases} m(\vec{r}) = m_0 e^{+\frac{\mu(\vec{r})}{k_B T}} \rightarrow \text{"Local" chemical potential} \Rightarrow \vec{\nabla} m = m_0 e^{+\frac{\mu}{k_B T}} \left(\frac{\vec{\nabla} \mu}{k_B T} \right) \\ \vec{F} = -\vec{\nabla} U \end{cases} \Rightarrow \frac{\vec{\nabla} m}{m} = + \frac{\vec{\nabla} \mu}{k_B T}$

$$\Rightarrow \vec{N} = -D \left(\frac{\vec{\nabla} \mu}{k_B T} \right) - \frac{\tau}{m} \vec{\nabla} U = \underbrace{-\left(\frac{k_B T \tau}{m} \right)}_D \frac{1}{k_B T} (\vec{\nabla} \mu) - \frac{\tau}{m} \vec{\nabla} U$$

$$\vec{N} = -\frac{\tau}{m} \vec{\nabla} \left(\mu(\vec{r}) + U(\vec{r}) \right)$$

Shows why chemical potential is called a potential: Diffusion can be rechecked motion arising from the gradient of μ , just like drift is motion arising from the gradient of a potential.

From $\frac{\partial m}{\partial t} = -\vec{\nabla} \cdot (m \vec{N})$ we get

$$\Rightarrow \frac{\partial \mu}{\partial t}(\vec{r}, t) = \frac{\tau}{m} (\vec{\nabla} \mu) \cdot \vec{\nabla} (\mu + U) + \frac{k_B T \tau}{m} \nabla^2 (\mu + U)$$

Drift-diffusion equation
Describes non-equilibrium behavior of carriers in semiconductors

due to free electrons

Relationship between heat conductivity and electrical conductivity :

$$\begin{cases} \vec{Q} = n \bar{E} \vec{v} \\ \vec{J} = n q \vec{v} \end{cases}$$

$$K = \frac{D_n C_v}{V} = \frac{1}{3} N_F^2 \tau \frac{C_v}{V}$$

Use Sommerfeld

$$\text{relation: } C_v = \frac{\pi^2}{2} \frac{k_B T}{E_F} k_B N = \frac{\pi^2}{2} \frac{k_B T}{\frac{1}{2} m N_F^2} k_B N$$

$$K = \frac{1}{3} N_F^2 \left(\frac{m \sigma}{e^2 n} \right) \frac{\pi^2 k_B^2 T N}{m N_F^2 V} = \frac{\pi^2}{3} \frac{k_B^2 T}{e^2} \sigma //$$

$$F_{rms} = \frac{m e^2 \tau}{m}$$

$$K = \frac{\pi^2}{3} \frac{k_B^2 T}{e^2} \sigma$$

Wiedemann-Franz law

